Product data sheet

1. Product profile

1.1 General description

General-purpose Zener diodes in a SOD323F (SC-90) very small and flat lead Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- Non-repetitive peak reverse power dissipation: ≤ 180 W
- Total power dissipation: ≤ 500 mW
- Very small plastic package suitable for surface-mounted design
- Low differential resistance
- AEC-Q101 qualified

1.3 Applications

General regulation functions

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage	$I_F = 100 \text{ mA}$	<u>[1]</u> _	-	1.1	V
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[2] _	-	500	mW

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

2. Pinning information

Table 2. Pinning

	3		
Pin	Description	Simplified outline	Graphic symbol
1	cathode	[1]	
2	anode	1 2	1 2 2

^[1] The marking bar indicates the cathode.



^[2] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
TDZxJ series	SC-90	plastic surface-mounted package; 2 leads	SOD323F

4. Marking

Table 4. Marking codes

Type number	Marking code	Type number	Marking code
TDZ2V4J	3A	TDZ9V1J	3Q
TDZ2V7J	3B	TDZ10J	3R
TDZ3V0J	3C	TDZ11J	3S
TDZ3V3J	3D	TDZ12J	3T
TDZ3V6J	3E	TDZ13J	3U
TDZ3V9J	3F	TDZ15J	3V
TDZ4V3J	3G	TDZ16J	3W
TDZ4V7J	3H	TDZ18J	3Y
TDZ5V1J	3J	TDZ20J	3Z
TDZ5V6J	JQ	TDZ22J	4A
TDZ6V2J	3K	TDZ24J	4B
TDZ6V8J	3L	TDZ27J	4C
TDZ7V5J	3N	TDZ30J	4D
TDZ8V2J	3P	-	-

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
I _F	forward current		-	250	mA
I _{ZSM}	non-repetitive peak reverse current		[1] -	see Table 8 and 10	
P _{ZSM}	non-repetitive peak reverse power dissipation		<u>[1]</u>		
	TDZ2V4J to TDZ5V6J		-	180	W
	TDZ6V2J to TDZ6V8J		-	100	W
	TDZ7V5J to TDZ30J		-	40	W
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$	[2] _	500	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-55	+150	°C
T_{stg}	storage temperature		-65	+150	°C

^[1] $t_D = 100 \mu s$; square wave; $T_i = 25 \,^{\circ}C$ before surge.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	<u>[1]</u> -	-	250	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point		[2] -	-	25	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 16 mm².

7. Characteristics

Table 7. Characteristics

 $T_i = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{F}	forward voltage		<u>[1]</u>			
		I _F = 10 mA	-	-	0.9	V
		$I_F = 100 \text{ mA}$	-	-	1.1	V

^[1] Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$

^[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 16 mm².

^[2] Soldering point of cathode tab.

Table 8. Characteristics per type; Zener TDZ2V4J to Zener TDZ24J

 $T_i = 25$ °C unless otherwise specified.

TDZxxxJ	Workin V _Z (V)	g voltage	Differentia resistance r _{dif} (Ω)		Revers I _R (μΑ)	e current	Tempe coeffic S _Z (mV	ient capacitance		Non-repetitive peak reverse current I _{ZSM} (A) ^[2]
	$I_Z = 5 \text{ m}$	ıΑ	I _Z = 1 mA	I _Z = 5 mA			I _Z = 5 n	ıΑ		
	Min	Max	Max	Max	Max	V _R (V)	Min	Max	Max	Max
2V4	2.35	2.45	400	100	50	1.0	-3.5	0	450	15
2V7	2.65	2.75	450	100	20	1.0	-3.5	0	440	15
3V0	2.94	3.06	500	95	10	1.0	-3.5	0	425	15
3V3	3.23	3.37	500	95	5	1.0	-3.5	0	410	15
3V6	3.53	3.67	500	90	5	1.0	-3.5	0	390	15
3V9	3.82	3.98	500	90	3	1.0	-3.5	0	370	15
4V3	4.21	4.39	600	90	3	1.0	-3.5	0	350	15
4V7	4.61	4.79	500	80	3	2.0	-3.5	0.2	325	15
5V1	5.00	5.20	480	60	2	2.0	-2.7	1.2	300	15
5V6	5.49	5.71	400	40	10	2.5	-2	2.5	275	15
6V2	6.08	6.32	150	10	3	4.0	0.4	3.7	250	12
6V8	6.66	6.94	80	15	2	4.0	1.2	4.5	215	12
7V5	7.5	7.65	80	10	1	5.0	2.5	5.3	170	4.0
8V2	8.04	8.36	80	10	0.70	5.0	3.2	6.2	150	4.0
9V1	8.92	9.28	100	10	0.50	6.0	3.8	7.0	120	3.0
10	9.80	10.20	150	10	0.20	7.0	4.5	8.0	110	3.0
11	10.80	11.20	150	10	0.10	8.0	5.4	9.0	108	2.5
12	11.80	12.20	150	10	0.10	8.0	6.0	10	105	2.5
13	12.70	13.30	170	10	0.10	8.0	7.0	11	103	2.5
15	14.70	15.30	200	15	0.05	10.5	9.2	13	99	2.0
16	15.70	16.30	200	20	0.05	11.2	10.4	14	97	1.5
18	17.6	18.4	225	20	0.05	12.6	12.4	16	93	1.5
20	19.6	20.4	225	20	0.05	14.0	14.4	18	88	1.5
22	21.6	22.4	250	25	0.05	15.4	16.4	20	84	1.25
24	23.5	24.5	250	30	0.05	16.8	18.4	22	80	1.25

^[1] $f = 1 \text{ MHz}; V_R = 0 \text{ V}$

Table 9. Characteristics per type; Zener TDZ5V6J

 $T_j = 25$ °C unless otherwise specified.

TDZxxxJ	Working voltage		Differential resi	stance	Temperature coefficient	
	V _Z (V)		r_{dif} (Ω)		S _Z (mV/K)	
	I _Z = 10 mA		I _Z = 0.5 mA	I _Z = 10 mA	I _Z = 5 mA	
	Min	Max	Max	Max	Min	Max
5V6	5.20	6.00	500	7	-1.7	2.8

TDZXJ_SER

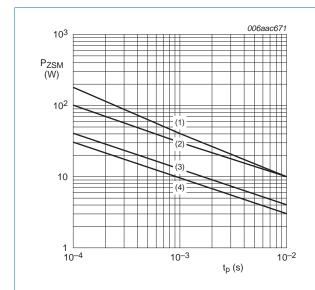
^[2] t_p = 100 μs ; square wave; T_j = 25 $^{\circ} C$ before surge.

Table 10. Characteristics per type; Zener TDZ27J to Zener TDZ30J

 $T_i = 25$ °C unless otherwise specified.

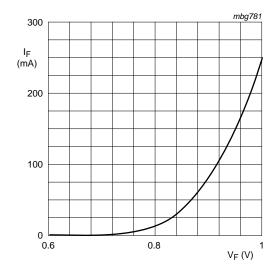
TDZxxxJ	Working V _Z (V)	yoltage	Differential r _{dif} (Ω)	resistance	current coefficient S _Z (mV/K)		ent coefficient		Diode capacitance C _d (pF)[1]	Non-repetitive peak reverse current I _{ZSM} (A)[2]
	I _Z = 2 m/	A	$I_Z = 0.5 \text{ mA}$	I _Z = 2 mA			I _Z = 2 m	ıA		
	Min	Max	Max	Max	Max	V _R (V)	Min	Max	Max	Max
27	26.5	27.5	250	40	0.05	18.9	21.4	25.3	73	1
30	29.4	30.6	250	40	0.05	21	24.4	29.4	66	1

- [1] $f = 1 \text{ MHz}; V_R = 0 \text{ V}$
- [2] $t_p = 100 \mu s$; square wave; $T_i = 25 \,^{\circ}C$ before surge.



- (1) TDZ2V4J to TDZ5V6J
- (2) TDZ6V2J to TDZ6V8J
- (3) TDZ7V5J to TDZ30J; T_j = 25 °C before surge
- (4) TDZ7V5J to TDZ30J; $T_j = 150$ °C before surge

Fig 1. Non-repetitive peak reverse power dissipation as a function of pulse duration; maximum values



T_j = 25 °C

Fig 2. Forward current as a function of forward voltage; typical values

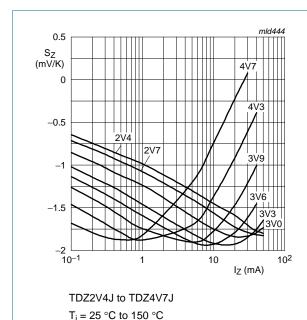
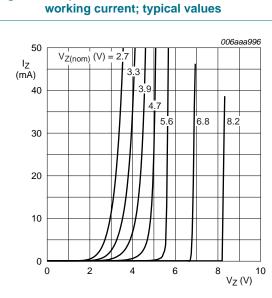
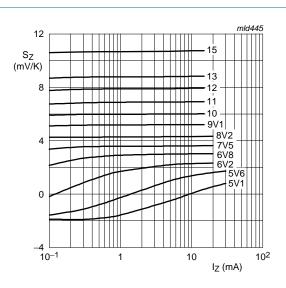


Fig 3. Temperature coefficient as a function of working current: typical values



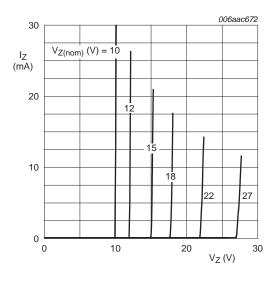
TDZ2V7J to TDZ6V6J $T_i = 25 \text{ °C}$

Fig 5. Working current as a function of working voltage; typical values



TDZ5V1J to TDZ15J $T_i = 25$ °C to 150 °C

Fig 4. Temperature coefficient as a function of working current; typical values



TDZ10J to TDZ27J

T_i = 25 °C

Fig 6. Working current as a function of working voltage; typical values

8. Test information

8.1 Quality information

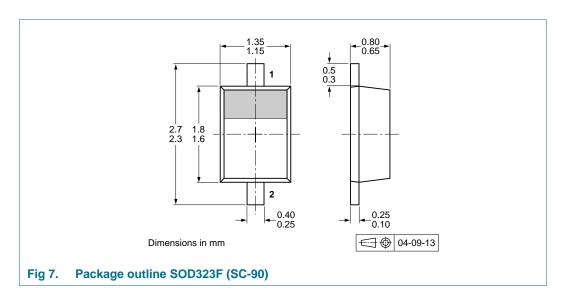
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

TDZXJ_SER

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9. Package outline



10. Packing information

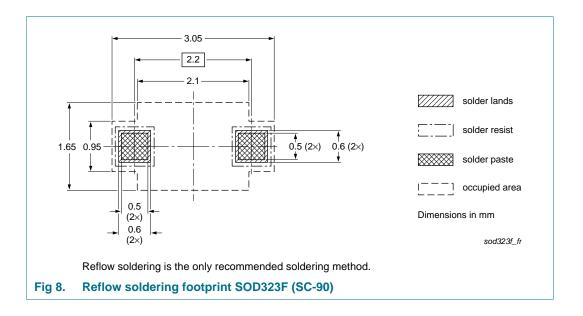
Table 11. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing qu	uantity
			3000	10000
TDZxJ series	SOD323F	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see Section 14.

11. Soldering



12. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
TDZXJ_SER v.2	20110729	Product data sheet	-	TDZ5V6J v.1
Modifications:	TDZ4V3J, 1 TDZ10J, TE	numbers TDZ2V4J, TDZ2 FDZ4V7J, TDZ5V1J, TDZ6 DZ11J, TDZ12J, TDZ13J, T DZ27J and TDZ30J.	V2J, TDZ6V8J, TDZ7V5	J, TDZ8V2J, TDZ9V1J,
	 Added <u>Table</u> 	<u>e 8</u> to <u>10</u> .		
	 Updated <u>Fig</u> 	gure 1 to 4 and added Figu	<u>ire 5</u> and <u>6</u> .	
TDZ5V6J v.1	20100823	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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TDZxJ series

Single Zener diodes

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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